NSN 5962-01-414-8327



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-414-8327 **Body Length:** 0.560 inches **Body Width:** 0.358 inches **Body Height:** 0.120 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Electrostatic sensitive and monolithic and tested to mil-std-883 and burn in **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Feat **Case Outline Source And Designator:** C-11 bs 3934 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuits, memory, digital, cmos 16k x 4 bits sram, (std power), monolithic silicon **Voltage Rating And Type Per Characteristic:** 0.5 volts total supply and 7.0 volts total supply **Time Rating Per Chacteristic:** 45.00 nanoseconds access **Memory Device Type:** Ram **Special Features:** Esd, sram, standard power **Test Data Document:**

96909-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 leadless

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Memory Microcircuit - Page 2 of 2



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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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